High Photovoltaic Performance of As-casting Device Based on New Quinoxaline-based Donor-Acceptor Copolymers

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MW Averages

Peak No	Mp	Mn	Mw	Mz	Mz+1	Mv	PD
1	108129	45919	169254	410043	654387	140562	3.68593

Processed Peaks

Peak No	Name	Start RT (mins)	Max RT (mins)	End RT (mins)	Pk Height (mV)	% Height	Area (mV.secs)	% Area
1		16.58	19.38	22.93	17.4603	100	3343.07	100

(b)



MW Averages

Peak No	Mp	Mn	Mw	Mz	Mz+1	Mv	PD		
1	70281	40304	108837	223197	341242	94161	2.7004		
Processed	Peaks								
Peak No	Name	Start RT (mins)	Max RT (mins)	End RT (mins)	Pk Heigl (mV)	ht %H	leight	Area (mV.secs)	% Area
1		17.17	19.78	22.68	3.0904	1	100	518.688	100



Figure S1 GPC plot of polymers: (a) PBDT-DFQX-TTSEH (b) PBDT-DFQX-TTSC8

Figure S2 TGA plots of the polymers with a heating rate of 10 C min⁻¹ under a N_2 atmosphere.

(a)



Figure S3 Thin film cyclic voltammograms of PBDTTS-EH-Qx and PBDTTS-C8-Qx in 0.1 M Bu_4NPF_6 acetonitrile solution at a scan rate of 100 mV·s⁻¹



Figure S4 Energy level diagrams for PBDT-DFQX-TT, PBDT-DFQX-TTSEH and PBDT-DFQX-TTSC8



Figure S5 Current density–voltage characteristics of the PSCs based on polymer: $PC_{71}BM$ blends with different treatment under illumination of AM1.5, 100 mW cm⁻²



Figure S6 $J^{1/2} \sim V_{\text{eff}}$ characteristics for the devices based on the blend films. Solid lines were the fitting lines of the data.



Figure S7 AFM topography ($2.5 \times 2.5 \mu m^2$) of blend films treat both with DIO and thermal annealing. (a) for PBDT-DFQX-TTSEH (b) for PBDT-DFQX-TTSC8

Table S1 Photovoltaic performances of the PSCs based on polymer/PC71BM

under the illumination of AM1.5G, 100 mW · cm⁻².

Polymer	Ratio ^a	Treatment	$V_{oc}(V)$	$(mA \cdot cm^{-2})$	FF(%)	PCE ^b (%)
)		
EH	1:1.2	3%DIO,TA	0.83	12.05	59.11	$5.94(5.47 \pm 0.36)$
C8	1:1.2	3%DIO,TA	0.81	14.04	61.54	$6.9(6.80 \pm 0.17)$

^a Polymer/PC₇₁BM weight ratio. ^b Optimized data. Average data were in the parentheses and obtained from 10 devices.



Figure S8 13C-NMR of BDT-TSC8



Figure S10 1H-NMR of BDT-TSC8-2Sn







Figure S14 1H-NMR of DFQx-TEH-2T-2Br



Figure S16 1H-NMR of PBDT-DFQx-TTSEH